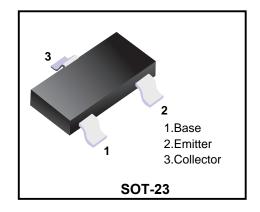


NPN Silicon Epitaxial Planar Transistor

Low saturation medium current application Suitable for low voltage large current drivers

Marking Code			
MMBTSD123	Y2		



Absolute Maximum Ratings (Ta=25℃)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	20	V
Collector Emitter Voltage	V _{CEO}	15	V
Emitter Base Voltage	V_{EBO}	6.5	V
Collector Current	Ic	1	А
Power Dissipation	P _{tot}	200	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _S	- 55 to + 150	°C

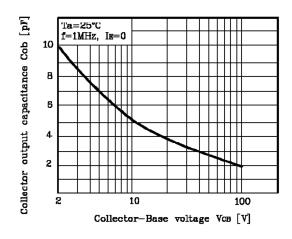
Electrical Characteristics (Ta=25° unless otherwise specified.)

Parameter	Symbol	Min.	Тур.	Max.	Unit
DC Current Gain at $V_{CE} = 1 \text{ V}$, $I_C = 100 \text{ mA}$	h _{FE}	150	-	_	-
Collector Cutoff Current at V _{CB} = 20 V	I _{CBO}	-	-	100	nA
Emitter Cutoff Current at V _{EB} = 6 V	I _{EBO}	-	-	100	nA
Collector Base Breakdown Voltage at $I_C = 50 \mu A$	V _{(BR)CBO}	20	-	-	V
Collector Emitter Breakdown Voltage at I _C = 1 mA	V _{(BR)CEO}	15	-	-	V
Emitter Base Breakdown Voltage at I _E = 50 μA	V _{(BR)EBO}	6.5	-	_	V
Collector Emitter Saturation Voltage at $I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$	V _{CE(sat)}	-	-	0.3	V
Transition Frequency at $V_{CE} = 5 \text{ V}$, $I_C = 50 \text{ mA}$	f⊤	-	260	_	MHz
Output Capacitance at $V_{CB} = 10 \text{ V}$, $f = 1 \text{ MHz}$	Сов	-	5	_	pF

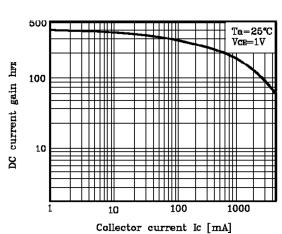


Typical Characteristics

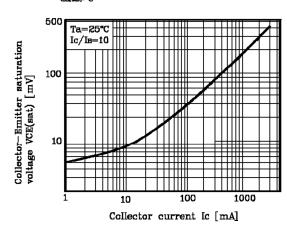




$\boldsymbol{h_{FE}}\boldsymbol{J_{C}}$



$V_{\text{CE(sat)}}I_{\text{C}}$



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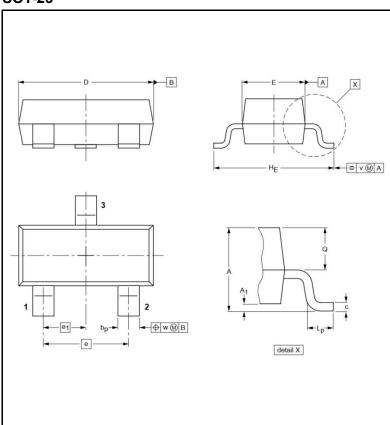


Ordering information

Package	Packing Description	Base Quantity	Packing Quantity
SOT-23	Tape/Reel,7"reel	3000pcs/Reel	24000PCS/Box 120000PCS/Carton

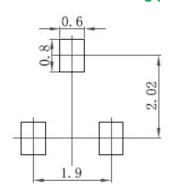
Package Dimensions

SOT-23



Dim.	Millimeter (mm)		mil		
	Min.	Max.	Min.	Max.	
Α	0.9	1.15	35	45	
A1	0.1		3.9)	
bp	0.38	0.48	15	19	
С	0.09	0.15	3.54	5.9	
D	2.8	3.0	110	118	
Е	1.2	1.4	47	55	
Е	1.9		75		
E1	0.95		37	,	
HE	2.1	2.55	83	100	
Lp	0.15	0.45	5.9	18	
Q	0.45	0.55	18	22	
V	0.2		7.9		
W	0.1		4		

The recommended mounting pad size





Disclaimer

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